SCS208AJ

SiC Schottky Barrier Diode

Datasheet

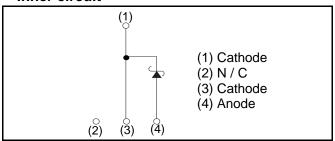
V_R	650V
I _F	8A
Q_{C}	13nC

Outline LPT(L) <TO-263AB> (2) (3) (4)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

•Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

	Packaging	Embossed tape
	Reel size (mm)	330
Type	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1 000
	Packing code	TLL
	Marking	SCS208AJ

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V _R	650	V
Continuous forward	current (T _c = 135°C)	l _F	8	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		30	А
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	23	А
	PW=10μs square, T _j =25°C		110	А
Repetitive peak forward current		I _{FRM}	35 ^{*1}	А
PW=10ms, T _j =25°C		۲.2 r.	4.3	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	2.6	A ² s
Total power dissipation		P _D	62 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_i = 25°C)

Parameter	Symbol	Conditions	Values			l lmit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =1.6mA	650	-	-	V
	V _F	I _F =8A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =8A,T _j =150°C	-	1.55	-	V
		I _F =8A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	1.6	160	μΑ
		V _R =600V,T _j =150°C	-	24	-	μΑ
		V _R =600V,T _j =175°C	-	56	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	290	-	pF
		V _R =600V,f=1MHz	-	30	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	13	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	13	-	ns

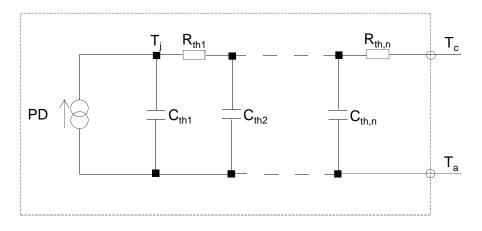
Thermal characteristics

Parameter	Symbol	Conditions —	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{th(j-c)}$	-	-	1.8	2.4	°C/W

● Typical Transient Thermal Characteristics

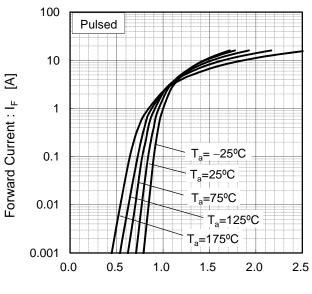
Symbol	Value	Unit
R _{th1}	6.93E-02	
R _{th2}	1.12E+00	K/W
R _{th3}	6.09E-01	

Symbol	Value	Unit
C_{th1}	1.30E-03	
C _{th2}	5.48E-04	Ws/K
C _{th3}	3.16E-02	



•Electrical characteristic curves

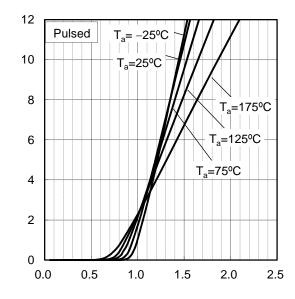
Fig.1 V_F - I_F Characteristics



Forward Voltage : V_F [V]

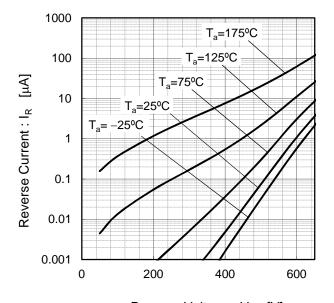
Fig.2 V_F - I_F Characteristics

Forward Current: I_F [A]



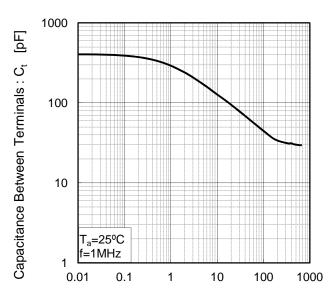
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

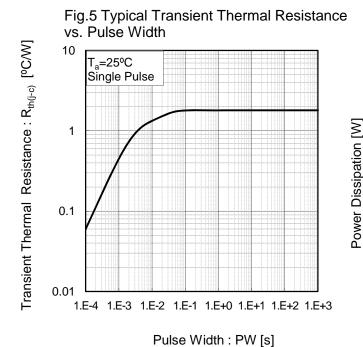
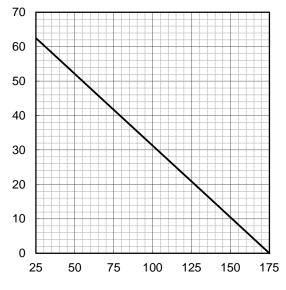
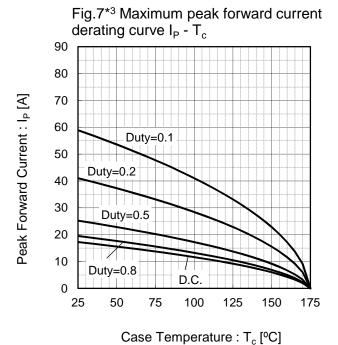


Fig.6 Power Dissipation



Case Temperature : T_c [°C]



*3 Based on max Vf, max R_{th(i-c)}

excluding D.C. curve.

Valid for switching of above 10kHz,

derating curve I_P - T_c (Not guaranteed) 90 80 Duty=0.1 Peak Forward Current : I_P [A] 70 60 Duty=0.2 50 40 Duty=0.5 30 20 10 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

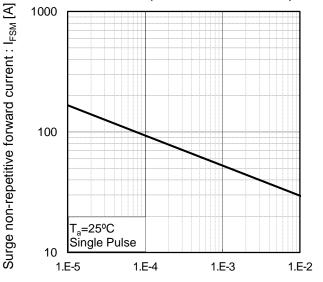
Fig.8*4 Typical peak forward current

Case Temperature : T_c [°C] *4 Based on typ Vf, typ $R_{th(j-c)}$ Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve



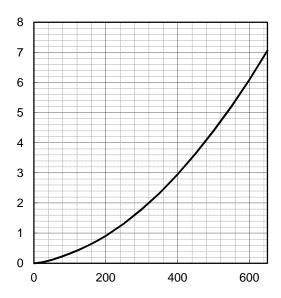
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

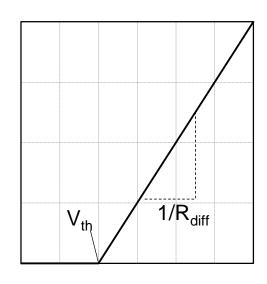


Capacitance stored energy : $E_C[\mu J]$

Reverse Voltage : V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\ T_{j}\ \right) = a_{0} + a_{1}\,T_{j} \\ &R_{diff}\left(\ T_{j}\ \right) = b_{0} + b_{1}\,T_{j} + b_{2}\,T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a ₀	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	4.98E-02	Ω
b ₁	1.28E-04	Ω/°C
b ₂	1.35E-06	Ω /°C ²

 T_i in °C; -55 °C < T_i < °C; I_F < 16 A

Forward Current: IF

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